

1000W, 10V - 100V Surface Mount Transient Voltage Suppressor

FEATURES FEATURES

- Low profile package
- Ideal for automated placement
- Glass passivated junction
- Built-in strain relief
- Excellent clamping capability
- Fast response time: Typically less than 1.0ps from 0 volt to BV min
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

KEY PARAMETERS

PARAMETER	VALUE	UNIT
V_{WM}	8.55 – 85.5	V
V_{BR} (uni-directional)	9.5 - 105	V
V_{BR} (bi-directional)	9.5 - 105	V
P_{PPSM}	1000	W
$T_{J\ MAX}$	175	°C
Package	DO-214AA (SMB)	
Configuration	Single die	

APPLICATIONS

- Switching mode power supply (SMPS)
- Adapters
- TV
- Monitor



MECHANICAL DATA

- Case: DO-214AA (SMB)
- Molding compound meets UL 94V-0 flammability rating
- Moisture sensitivity level: level 1, per J-STD-020
- Part no. with suffix "H" means AEC-Q101 qualified
- Packing code with suffix "G" means green compound (halogen-free)
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 2 whisker test
- Polarity: As marked
- Weight: 0.11 g (approximately)



DO-214AA (SMB)

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	PART NUMBER	UNIT
Non-repetitive peak impulse power dissipation with 10/1000us waveform	P_{PPSM}	1000	W
Steady state power dissipation at $T_A=25^\circ\text{C}$ ⁽¹⁾	P_{tot}	5	W
Peak forward surge current, 8.3 ms single half sine-wave superimposed on rated load	I_{FSM}	100	A
Forward Voltage @ $I_F=50\text{A}$ for Uni-directional only ⁽²⁾	V_F	3.5/5.0	V
Junction temperature	T_J	-55 to +175	°C
Storage temperature	T_{STG}	-55 to +175	°C

Notes:

1. Non-repetitive Current Pulse Per Fig. 3 and Derated above $T_A=25^\circ\text{C}$ Per Fig. 2
2. $V_F=3.5\text{V}$ for Devices of $V_{BR} \leq 50\text{V}$ and $V_F=5.0\text{V}$ Max. for Devices $V_{BR} > 50\text{V}$

Devices for Bipolar Applications

1. For Bidirectional use CA suffix

THERMAL PERFORMANCE

PARAMETER	SYMBOL	LIMIT	UNIT
Junction-to-lead thermal resistance	$R_{\theta JL}$	20	°C/W
Junction-to-ambient thermal resistance	$R_{\theta JA}$	100	°C/W

ELECTRICAL SPECIFICATIONS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Device	Device Marking Code	Breakdown Voltage $V_{BR}@I_T$ (V)		Test Current I_T (mA)	Stand-Off Voltage $@V_{WM}$ (V)	Maximum Reverse Leakage $@V_{WM}$ (μA)	Maximum Peak impulse Current I_{PP} (A) (Note 2)	Maximum Clamping Voltage $V_C@I_{PP}$ (V)
		Min.	Max.					
1KSMB10A	A10E	9.5	10.5	1.0	8.55	10.0	69.0	14.5
1KSMB10CA	N10E							
1KSMB11A	A10F	10.5	11.6	1.0	9.40	5.0	64.1	15.6
1KSMB11CA	N10F							
1KSMB12A	A10G	11.4	12.6	1.0	10.2	5.0	59.9	16.7
1KSMB12CA	N10G							
1KSMB13A	A10H	12.4	13.7	1.0	11.1	5.0	54.9	18.2
1KSMB13CA	N10H							
1KSMB15A	A10I	14.3	15.8	1.0	12.8	5.0	47.2	21.2
1KSMB15CA	N10I							
1KSMB16A	A10J	15.2	16.8	1.0	13.6	1.0	44.4	22.5
1KSMB16CA	N10J							
1KSMB18A	A10K	17.1	18.9	1.0	15.3	1.0	39.2	25.5
1KSMB18CA	N10K							
1KSMB20A	A10L	19.0	21.0	1.0	17.1	1.0	36.1	27.7
1KSMB20CA	N10L							
1KSMB22A	A10M	20.9	23.1	1.0	18.8	1.0	32.7	30.6
1KSMB22CA	N10M							
1KSMB24A	A10N	22.8	25.2	1.0	20.5	1.0	30.1	33.2
1KSMB24CA	N10N							
1KSMB27A	A10O	25.7	28.4	1.0	23.1	1.0	26.7	37.5
1KSMB27CA	N10O							
1KSMB30A	A10P	28.5	31.5	1.0	25.6	1.0	24.2	41.4
1KSMB30CA	N10P							
1KSMB33A	A10Q	31.4	34.7	1.0	28.2	1.0	21.9	45.7
1KSMB33CA	N10Q							
1KSMB36A	A10R	34.2	37.8	1.0	30.8	1.0	20.0	49.9
1KSMB36CA	N10R							
1KSMB39A	A10S	37.1	41.0	1.0	33.3	1.0	18.6	53.9
1KSMB39CA	N10S							
1KSMB43A	A10T	40.9	45.2	1.0	36.8	1.0	16.9	59.3
1KSMB43CA	N10T							
1KSMB47A	A10U	44.7	49.4	1.0	40.2	1.0	15.4	64.8
1KSMB47CA	N10U							
1KSMB51A	A10V	48.5	53.6	1.0	43.6	1.0	14.3	70.1
1KSMB51CA	N10V							
1KSMB56A	A10W	53.2	58.8	1.0	47.8	1.0	13.0	77.0
1KSMB56CA	N10W							
1KSMB62A	A10X	58.9	65.1	1.0	53.0	1.0	11.8	85.0
1KSMB62CA	N10X							
1KSMB68A	A10Y	64.6	71.4	1.0	58.1	1.0	10.9	92.0
1KSMB68CA	N10Y							

ELECTRICAL SPECIFICATIONS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Device	Device Marking Code	Breakdown voltage $V_{BR}@I_T$ (V) (Note 1)		Test current I_T (mA)	Stand-Off Voltage $@V_{WM}$ (V)	Maximum Reverse leakage $@V_{WM}$ (μA)	Maximum peak impulse current I_{PP} (A) (Note 2)	Maximum clamping voltage $V_C@I_{PP}$ (V)
		Min.	Max.					
1KSMB75A	A10Z	71.3	78.8	1.0	64.1	1.0	9.7	103
1KSMB75CA	N10Z							
1KSMB82A	B10A	77.9	86.1	1.0	70.1	1.0	8.8	113
1KSMB82CA	O10A							
1KSMB91A	B10B	86.5	95.5	1.0	77.8	1.0	8.0	125
1KSMB91CA	O10B							
1KSMB100A	B10C	95	105	1.0	85.5	1.0	7.3	137
1KSMB100CA	O10C							

Notes:

1. V_{BR} measure after I_T applied for 300 μs , I_T =square wave pulse or equivalent.
2. All terms and symbols are consistent with ANSI/IEEE C62.35.
3. For Bidirectional use CA suffix

ORDERING INFORMATION

PART NO.	PART NO. SUFFIX	PACKING CODE	PACKING CODE SUFFIX(*)	PACKAGE	PACKING
1KSMBxxxx (Note 1)	H	R5	G	SMB	850 / 7" Plastic reel
		R4		SMB	3,000 / 13" Paper reel
		M4		SMB	3,000 / 13" Plastic reel

Note :

1. "xxxx" defines voltage from 10V (1KSMB10A) to 100V (1KSMB100CA)

*: Optional available

EXAMPLE P/N

EXAMPLE P/N	PART NO.	PART NO. SUFFIX	PACKING CODE	PACKING CODE SUFFIX	DESCRIPTION
1KSMB39AHR5G	1KSMB39A	H	R5	G	AEC-Q101 qualified Green compound

CHARACTERISTICS CURVES

($T_A = 25^\circ\text{C}$ unless otherwise noted)

Fig1. Peak Pulse Power Rating Curve

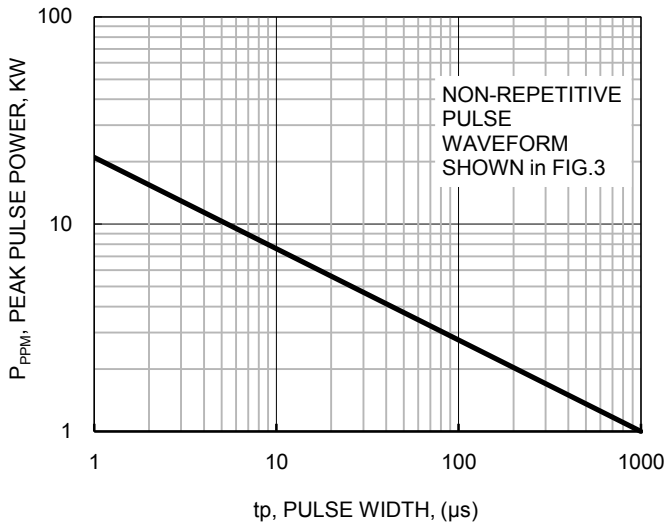


Fig2. Pulse Derating Curve

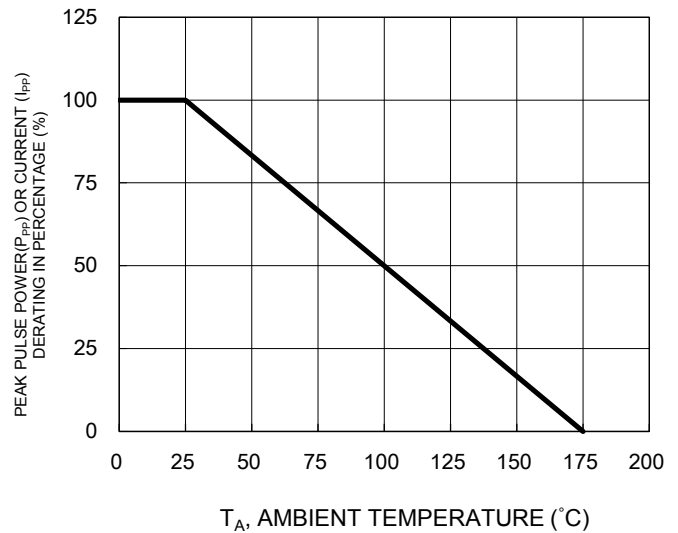


Fig3. Clamping Power Pulse Waveform

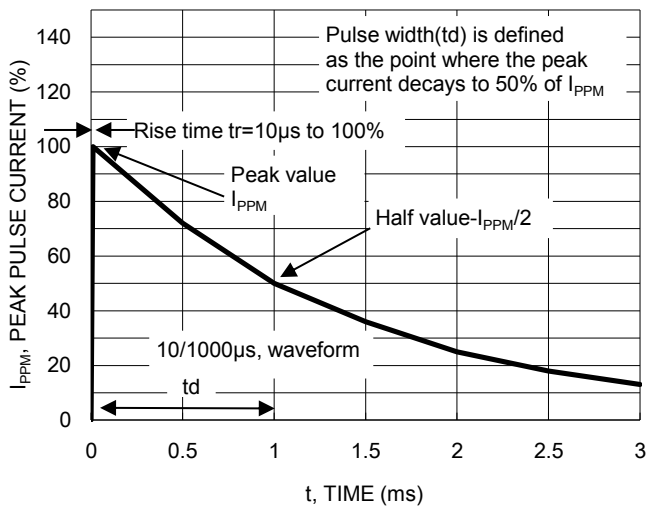


Fig4. Maximum Non-Repetitive Forward Surge Current Unidirectional Only

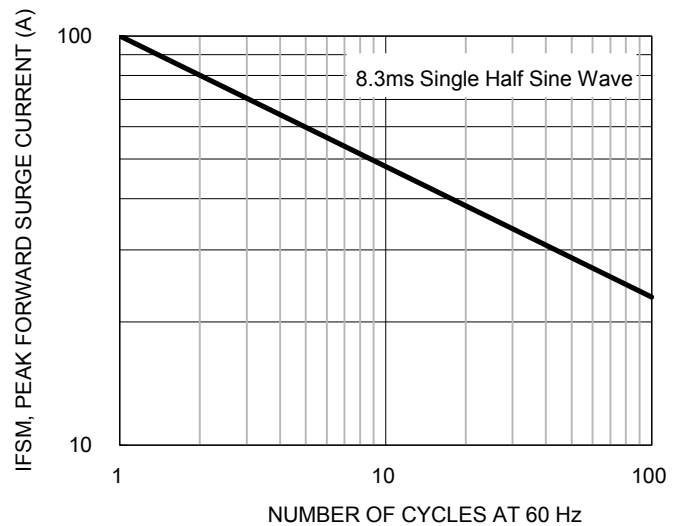
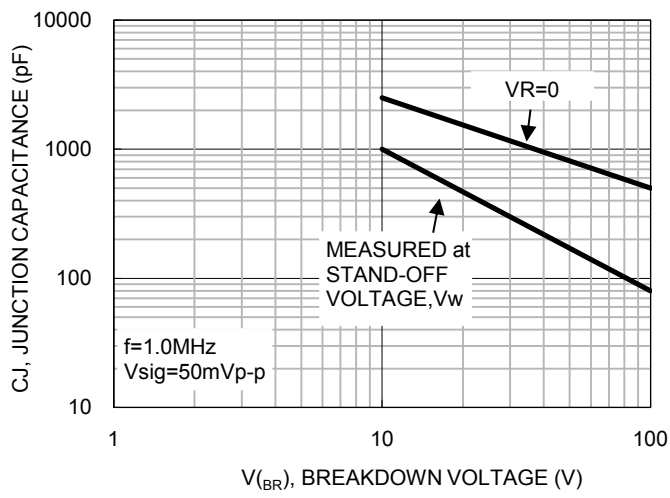
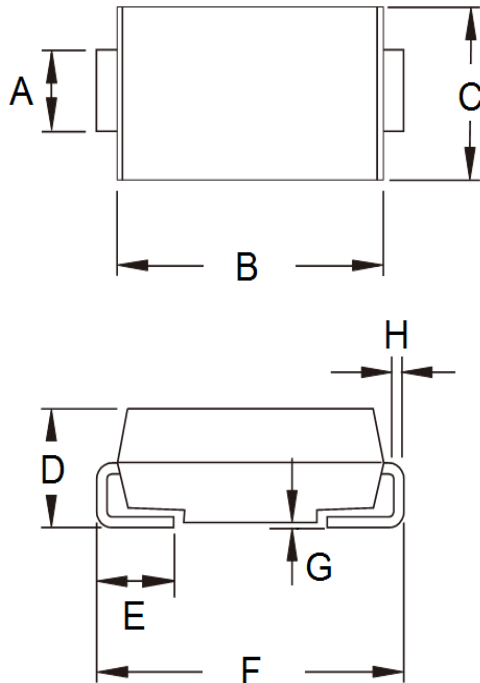


Fig5. Typical Junction Capacitance



PACKAGE OUTLINE DIMENSIONS

DO-214AA (SMB)



DIM.	Unit (mm)		Unit (inch)	
	Min	Max	Min	Max
A	1.95	2.20	0.077	0.087
B	4.05	4.60	0.159	0.181
C	3.30	3.95	0.130	0.156
D	1.95	2.65	0.077	0.104
E	0.75	1.60	0.030	0.063
F	5.10	5.60	0.201	0.220
G	0.05	0.20	0.002	0.008
H	0.15	0.31	0.006	0.012

SUGGESTED PAD LAYOUT



Symbol	Unit (mm)	Unit (inch)
A	2.3	0.091
B	2.5	0.098
C	4.3	0.169
D	1.8	0.071
E	6.8	0.268

MARKING DIAGRAM



P/N = Marking Code
 G = Green Compound
 YW = Date Code
 F = Factory Code

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